

Description

The DIODESTM AP7343Q is a low dropout regulator with high output voltage accuracy, low $R_{DS(ON)}$, high PSRR, low output noise and low quiescent current. This regulator is based on a CMOS process.

The AP7343Q includes a voltage reference, error amplifier, current limit circuit, and an enable input to turn it on and off. With the integrated resistor network, fixed output voltage versions can be delivered.

With its low power consumption and line and load transient responses, the AP7343Q is well suited for noise sensitive automotive applications.

The AP7343Q is packaged in SOT25 and W-DFN2020-6 (SWP) (Type A1) packages, which allow for the smallest footprint and dense PCB layout.

Features

- Low VIN and Wide VIN Range: 1.7V to 5.25V
- -40°C to +125°C Temperature Range
- Guaranteed Output Current: 300mA
- Vout Accuracy ±1%
- Ripple Rejection 75dB at 1kHz
- Low Output Noise, 60µVrms from 10Hz to 100kHz
- Quiescent Current as Low as 35µA
- Vout Fixed 0.9V to 3.6V
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The AP7343Q is suitable for automotive applications requiring specific change control; this part is AEC-Q100 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

Pin Assignments





W-DFN2020-6 (SWP) (Type A1)

Future Product

Applications

- Infotainment power supplies
- Automotive RF supplies
- Cameras
- Automotive POL in ADAS
- Automotive wireless communications
- Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
 - 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

Typical Applications Circuit





Pin Descriptions

| Pin M | Pin Number | | |
|-------|--------------------------------|-----------------|---|
| SOT25 | W-DFN2020-6 (SWP) (Type A1) | Pin Name | Function |
| 1 | 6 | V _{IN} | Power Input Pin |
| 2 | 3 | GND | Ground |
| 3 | 4 | EN | Enable Pin This pin must be driven either high or low and must not be floating. Driving this pin high enables the regulator, and pulling it low puts the regulator into shutdown mode. |
| 4 | 2, 5 | NC | No Connect Not connected internally; recommended to connect to GND to maximize PCB copper for thermal dissipation. |
| 5 | 1 | Vout | Power Output Pin |
| _ | EP | Expose Pad | In PCB layout, prefer to use large copper area to cover this pad for better thermal dissipation, then connect this area to GND or leave it open. However, do not use it as GND electrode function alone |

Functional Block Diagram



DIODES[™] AP7343DQ (With Discharge)



AP7343Q (Without Discharge)

| Symbol | Parameter | | Ratings | Unit |
|----------------------------------|--------------------------------|--|-------------------------------|------|
| ESD HBM | Human Body Mode ESD Protection | | > 2 | kV |
| ESD CDM | Charge Device Mod | el | ±500 | V |
| VIN | Input Voltage | | 6.0 | V |
| VEN | Input Voltage for EN Pin | | 6.0 | V |
| Vout | Output Voltage | | -0.3 to V _{IN} + 0.3 | V |
| lout | Output Current | | 400 | mA |
| 5 | SOT25 | SOT25 | 400 | |
| P _D Power Dissipation | | W-DFN2020-6 (SWP) (Type A1) (Wettable) | TBD | — mW |
| TJ | Operating Junction Temperature | | -40 to +150 | °C |
| T _{STG} | Storage Temperature | | -55 to +150 | °C |

Absolute Maximum Ratings (Note 4) ($@T_A = +25^{\circ}C$, unless otherwise specified.)

4. a). Stresses greater than those listed under Absolute Maximum Ratings can cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to Absolute Maximum Ratings for extended periods can affect device reliability.

b). Ratings apply to ambient temperature at +25°C. The JEDEC High-K board design used to derive this data was a 2inch x 2inch multilayer board with 1oz internal power and ground planes and 2oz copper traces on the top and bottom of the board.

Note:



Recommended Operating Conditions (@TA = +25°C, unless otherwise specified.)

| Symbol | Parameter | Min | Max | Unit |
|--------|---|-----|------|------|
| Vin | Input Voltage | 1.7 | 5.25 | V |
| lout | Output Current | 0 | 300 | mA |
| TJ | T _J Operating Junction Temperature | | +125 | °C |
| TA | Operating Ambient Temperature | -40 | +125 | °C |

Electrical Characteristics (@T_A = +25°C, V_{IN} = V_{OUT} + 1.0V, C_{IN} = C_{OUT} = 1.0µF, I_{OUT} = 1.0mA, unless otherwise specified.)

| Parameter | Condi | tion | | Min | Тур | Max | Unit |
|--|--|--|---------------------------|-------------------|---------|-------------------|--------|
| Input Voltage | $T_A = -40^{\circ}C \text{ to } +85^{\circ}C$ | | | 1.7 | | 5.25 | V |
| Output Voltage Accuracy (Note 5) | $V_{OUT}(T) \ge 2.0V, V_{IN} = V_{OUT}(T) + 1V$ $T_A = -1$ | | T _A = +25°C | Vouт(T) x 0.99 | Vout(T) | Vouт(T) x 1.01 | · V |
| Output voltage Accuracy (Note 5) | $V_{OUT}(T) < 2.0V, V_{IN} = V_{OUT}(T) + 1V$ $T_A = T_A = $ | | T _A = +25°C | Vоит(T) - 20mV | Vout(T) | Vouт(T) + 20mV | |
| Line Regulation (dVout/dVIN/Vout) | $V_{IN} = (V_{OUT} - N_{OM} + 1.0V)$ to 5 | 5.25V, Iout | = 1.0mA | _ | 0.02 | 0.1 | %/V |
| Load Regulation | VIN = VOUT - Nom + 1.0V, IOUT | = 1mA to | 300mA | — | 15 | 30 | mV |
| Quiescent Current (Note 6) | Iout = 0mA | | | — | 35 | 60 | μA |
| ISTANDBY | $V_{EN} = 0V$ (Disabled) | | | — | 0.01 | 1.0 | μA |
| Output Current | — | | | 300 | | — | mA |
| Fold-back Short Current (Note 7) | VOUT Short to Ground | | | — | 55 | — | mA |
| PSRR (Note 8) | $V_{IN} = (V_{OUT} + 1V) V_{DC} + 0.2V$ $V_{OUT} \ge 1.8V$, $I_{OUT} = 30mA$ | ′р-рАС | f = 1kHz | _ | 75 | — | dB |
| Output Noise Voltage (Notes 8 & 9) | BW = 10Hz to 100kHz, IOUT = | = 30mA | | _ | 60 | _ | µVrms |
| | 1 Iout = 300mA (SOT25) | Vout | = 0.9V | _ | 0.51 | 0.82 | V |
| | | 1.0V · | < Vouт ≤ 1.2V | _ | 0.46 | 0.72 | |
| | | 1.2V | < V _{OUT} ≤ 1.4V | _ | 0.39 | 0.60 | |
| | | 1.4V | < Vouт ≤ 1.7V | _ | 0.35 | 0.46 | |
| Dropout Voltage (Note 10) | | 1.7V - | < Vouт ≤ 2.1V | _ | 0.30 | 0.41 | |
| | | 2.1V | < V _{OUT} ≤ 2.5V | _ | 0.26 | 0.36 | |
| | | 2.5V | < V _{OUT} ≤ 3.0V | _ | 0.25 | 0.32 | |
| | | 3.0V | < Vout ≤ 3.6V | _ | 0.22 | 0.31 | |
| Output Voltage Temperature Coefficient | $I_{OUT} = 30$ mA, $T_A = -40^{\circ}$ C to + | -125°C | | — | ±30 | — | ppm/°C |
| Thermal Shutdown Threshold (TSHDN) | — | | | — | +150 | — | °C |
| Thermal Shutdown Hysteresis (THYS) | — | | | — | +20 | — | °C |
| EN Input Low Voltage | — | | | 0 | | 0.5 | V |
| EN Input High Voltage | — | | | 1.3 | _ | 5.25 | V |
| EN Input Leakage | V _{EN} = 0V, V _{IN} = 5.0V or V _{EN} = 5.0V, V _{IN} = 0V | | -1.0 | _ | +1.0 | μA | |
| On Resistance of N-Channel for Auto-Discharge (Note 11) | V _{IN} = 4.0V, V _{EN} = 0V (Disabled) | | — | 30 | — | Ω | |
| Thermal Resistance Junction to | SOT25 | | | — | 179 | — | |
| Ambient (0JA) | W-DFN2020-6 (SWP) (Type | A1) (Wetta | ble) | — | TBD | — | °C/W |
| Thermal Resistance Junction to | SOT25 | | | — | 52 | — | |
| Case (θJC) | W-DFN2020-6 (SWP) (Type | W-DFN2020-6 (SWP) (Type A1) (Wettable) | | | TBD | — | 1 |

5. Potential multiple grades based on following output voltage accuracy. Notes:

6. Quiescent current defined here is the difference in current between the input and the output.

Short circuit current is measured with V_{OUT} pulled to GND.
This specification is guaranteed by design.
To make sure lowest environment noise minimizes the influence on noise measurement.
Dropout voltage is the voltage difference between the input and the output at which the output voltage drops 2% below its nominal value.
AP7343Q has two options for output, built-in discharge and non-discharge.



Typical Characteristics













































Line Transient Response Waveforms (I_{OUT} = 30mA, $t_R = t_F = 5\mu s$, $C_{IN} = None$, $C_{OUT1} = C_{OUT2} = 1\mu F$, $T_A = +25^{\circ}C$)







Load Transient Response Waveforms (VIN = VOUT + 1V, CIN = 1µF, TA = +25°C)





Load Transient Response Waveforms ($V_{IN} = V_{OUT} + 1V$, $C_{IN} = 1\mu$ F, $T_A = +25^{\circ}$ C)





AP7343Q

Typical Characteristics (continued)

Turn On & Off Waveforms (VIN = VOUT + 1V, CIN = 1 μ F, COUT = 1 μ F, TA = +25°C)





Application Information

Output Capacitor

An output capacitor (C_{OUT}) is required to improve transient response and maintain stability. The AP7343Q is stable with very-small ceramic-output capacitors. The ESR (equivalent series resistance) and capacitance drive the selection. If the application has large load variations, it is recommended to utilize low-ESR bulk capacitors. It is recommended to place ceramic capacitors as close as possible to the load, and the ground pin and care should be taken to reduce the impedance in the layout.

Input Capacitor

To prevent the input voltage from dropping during load steps, it is recommended to utilize an input capacitor (CIN). A minimum 0.47µF ceramic capacitor is recommended between VIN and GND pins to decouple input power supply glitch. This input capacitor must be located as close as possible to the device to ensure input stability and reduce noise. For PCB layout, a wide copper trace is required for both VIN and GND pins.

Enable Control

The AP7343Q is turned on by setting the EN pin high and is turned off by pulling it low. If this feature is not used, the EN pin should be tied to V_{IN} pin to keep the regulator output on at all times. To ensure proper operation, the signal source used to drive the EN pin must be able to swing above and below the specified turn-on/off voltage thresholds listed in the *Electrical Characteristics* section.

Short Circuit Protection

When V_{OUT} pin is short-circuited to GND, short-circuit protection is triggered and clamps the output current to approximately 60mA. This feature protects the regulator from overcurrent and damage due to overheating.

Layout Considerations

For good ground loop and stability, the input and output capacitors should be located close to the input, output, and ground pins of the device. The regulator ground pin should be connected to the external circuit ground to reduce voltage drop caused by trace impedance. Ground plane is generally used to reduce trace impedance. Wide trace should be used for large current paths from V_{IN} to V_{OUT} and load circuit.

ESR vs. Output Current

Ceramic type output capacitor is recommended for this series; however, the other output capacitors with low ESR also can be used. The relations between IoUT (output current) and ESR of an output capacitor are shown below. The stable region is marked as the hatched area in the graph.

Measurement conditions: Frequency Band: 10Hz to 2MHz, Temperature: -40°C to +125°C.





Ordering Information (Notes 12, 13 & 14)



| Part Number | Part Number Suffix | Package Code | Package | Packing | | |
|-----------------------|--------------------|--------------|-----------------------------|---------|----------------|--|
| | Fait Number Sumx | Fackage Code | rachaye coue rachaye | | Carrier | |
| AP7343Q-XXXW5-7 | -7 | W5 | SOT25 | 3000 | 7" Tape & Reel | |
| AP7343DQ-XXXW5-7 | -7 | W5 | SOT25 | 3000 | 7" Tape & Reel | |
| AP7343Q-XXXFDZW-7(*) | -7 | FDZW | W-DFN2020-6 (SWP) (Type A1) | 3000 | 7" Tape & Reel | |
| AP7343DQ-XXXFDZW-7(*) | -7 | FDZW | W-DFN2020-6 (SWP) (Type A1) | 3000 | 7" Tape & Reel | |

* Future Product

Notes: 12. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

13. Other output voltage variants may be available in 100mV steps. For more information, please contact your local Diodes Incorporated sales representative.

14. AP7343Q and AP7343DQ are qualified to AEC-Q100 grade 1 and are classified as "Automotive Compliant" supporting PPAP documentation. Automotive compliant and standard products are electrically and thermally the same, except where specified. For more information, please refer to https://www.diodes.com/quality/product-definitions/.



Marking Information

(1) SOT25



| Part Number | Package | Identification Code |
|-----------------|---------|---------------------|
| AP7343Q-09W5-7 | SOT25 | 7BQ |
| AP7343Q-10W5-7 | SOT25 | 7CQ |
| AP7343Q-11W5-7 | SOT25 | 7EQ |
| AP7343Q-12W5-7 | SOT25 | 7FQ |
| AP7343Q-15W5-7 | SOT25 | 7HQ |
| AP7343Q-18W5-7 | SOT25 | 7JQ |
| AP7343Q-185W5-7 | SOT25 | 7KQ |
| AP7343Q-25W5-7 | SOT25 | 7NQ |
| AP7343Q-27W5-7 | SOT25 | 7XQ |
| AP7343Q-28W5-7 | SOT25 | 7PQ |
| AP7343Q-29W5-7 | SOT25 | 8AQ |
| AP7343Q-30W5-7 | SOT25 | 7TQ |
| AP7343Q-33W5-7 | SOT25 | 7WQ |
| AP7343DQ-09W5-7 | SOT25 | 8BQ |
| AP7343DQ-10W5-7 | SOT25 | 8CQ |
| AP7343DQ-11W5-7 | SOT25 | 8EQ |
| AP7343DQ-12W5-7 | SOT25 | 8FQ |
| AP7343DQ-15W5-7 | SOT25 | 8KQ |
| AP7343DQ-18W5-7 | SOT25 | 8PQ |
| AP7343DQ-25W5-7 | SOT25 | 8XQ |
| AP7343DQ-27W5-7 | SOT25 | 8ZQ |
| AP7343DQ-28W5-7 | SOT25 | 6JQ |
| AP7343DQ-29W5-7 | SOT25 | 6MQ |
| AP7343DQ-30W5-7 | SOT25 | 6PQ |
| AP7343DQ-33W5-7 | SOT25 | 6TQ |



Marking Information (continued)

(2) W-DFN2020-6 (SWP) (Type A1)



 $\frac{XXXX}{Y} : \text{Identification Code}$ $\frac{Y}{Y} : \text{Year} : 0 \text{ to } 9 \text{ (ex: } 2 = 2022\text{)}$ $\frac{W}{Y} : \text{Week} : \text{A to } \text{Z} : \text{Week } 1 \text{ to } 26\text{;}$ a to z : Week 27 to 52; z represents Week 52 and 53 $\underline{X} : \text{Internal Code}$

| Part Number | Package | Identification Code |
|-------------------|-----------------------------|---------------------|
| AP7343Q-09FDZW-7 | W-DFN2020-6 (SWP) (Type A1) | 7BQ |
| AP7343Q-10FDZW-7 | W-DFN2020-6 (SWP) (Type A1) | 7CQ |
| AP7343Q-11FDZW-7 | W-DFN2020-6 (SWP) (Type A1) | 7EQ |
| AP7343Q-12FDZW-7 | W-DFN2020-6 (SWP) (Type A1) | 7FQ |
| AP7343Q-15FDZW-7 | W-DFN2020-6 (SWP) (Type A1) | 7HQ |
| AP7343Q-18FDZW-7 | W-DFN2020-6 (SWP) (Type A1) | 7JQ |
| AP7343Q-185FDZW-7 | W-DFN2020-6 (SWP) (Type A1) | 7KQ |
| AP7343Q-25FDZW-7 | W-DFN2020-6 (SWP) (Type A1) | 7NQ |
| AP7343Q-27FDZW-7 | W-DFN2020-6 (SWP) (Type A1) | 7XQ |
| AP7343Q-28FDZW-7 | W-DFN2020-6 (SWP) (Type A1) | 7PQ |
| AP7343Q-29FDZW-7 | W-DFN2020-6 (SWP) (Type A1) | 8AQ |
| AP7343Q-30FDZW-7 | W-DFN2020-6 (SWP) (Type A1) | 7TQ |
| AP7343Q-33FDZW-7 | W-DFN2020-6 (SWP) (Type A1) | 7WQ |
| AP7343DQ-09FDZW-7 | W-DFN2020-6 (SWP) (Type A1) | 8BQ |
| AP7343DQ-10FDZW-7 | W-DFN2020-6 (SWP) (Type A1) | 8CQ |
| AP7343DQ-11FDZW-7 | W-DFN2020-6 (SWP) (Type A1) | 8EQ |
| AP7343DQ-12FDZW-7 | W-DFN2020-6 (SWP) (Type A1) | 8FQ |
| AP7343DQ-15FDZW-7 | W-DFN2020-6 (SWP) (Type A1) | 8KQ |
| AP7343DQ-18FDZW-7 | W-DFN2020-6 (SWP) (Type A1) | 8PQ |
| AP7343DQ-25FDZW-7 | W-DFN2020-6 (SWP) (Type A1) | 8XQ |
| AP7343DQ-27FDZW-7 | W-DFN2020-6 (SWP) (Type A1) | 8ZQ |
| AP7343DQ-28FDZW-7 | W-DFN2020-6 (SWP) (Type A1) | 6JQ |
| AP7343DQ-29FDZW-7 | W-DFN2020-6 (SWP) (Type A1) | 6MQ |
| AP7343DQ-30FDZW-7 | W-DFN2020-6 (SWP) (Type A1) | 6PQ |
| AP7343DQ-33FDZW-7 | W-DFN2020-6 (SWP) (Type A1) | 6TQ |



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

(1) SOT25



| | SOT25 | | | |
|-------|----------------------|------|------|--|
| Dim | Min | Max | Тур | |
| Α | 0.35 | 0.50 | 0.38 | |
| В | 1.50 | 1.70 | 1.60 | |
| С | 2.70 | 3.00 | 2.80 | |
| D | - | - | 0.95 | |
| н | 2.90 | 3.10 | 3.00 | |
| J | 0.013 | 0.10 | 0.05 | |
| κ | 1.00 | 1.30 | 1.10 | |
| L | 0.35 | 0.55 | 0.40 | |
| Μ | 0.10 | 0.20 | 0.15 | |
| Ν | 0.70 | 0.80 | 0.75 | |
| α | 0° | 8° | - | |
| All D | All Dimensions in mm | | | |

(2) W-DFN2020-6 (SWP) (Type A1)



| w | W-DFN2020-6 (SWP) (Type A1) | | | |
|-----|--------------------------------|----------|------|--|
| Dim | Min | Max | Тур | |
| Α | 0.70 | 0.80 | 0.75 | |
| A1 | 0.00 | 0.05 | 0.02 | |
| A3 | 0 | .203 RE | F | |
| b | 0.25 | 0.35 | 0.30 | |
| D | 2.00 BSC | | | |
| D2 | 1.35 | 1.45 | 1.40 | |
| E | | 2.00 BSC |) | |
| E2 | 0.55 | 0.65 | 0.60 | |
| е | (|).65 BSC |) | |
| k | 0.20 | | | |
| L | 0.20 | 0.40 | 0.30 | |
| All | All Dimensions in mm | | | |

е

TERMINAL CROSS SECTION



Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

(1) SOT25



| Dimensions | Value (in mm) |
|------------|------------------|
| Z | 3.20 |
| G | 1.60 |
| Х | 0.55 |
| Y | 0.80 |
| C1 | 2.40 |
| C2 | 0.95 |

(2) W-DFN2020-6 (SWP) (Type A1)



| Dimensions | Value (in mm) |
|------------|------------------|
| С | 0.650 |
| C1 | 2.100 |
| X | 0.350 |
| X1 | 1.400 |
| Y | 0.800 |
| Y1 | 0.600 |

Mechanical Data

- Moisture Sensitivity: Level 1 Per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 3
- Weight:
 - SOT25: 0.016 grams (Approximate)
 - W-DFN2020-6 (SWP) (Type A1): 0.010 grams (Approximate)



Tape Orientation

For AP7343Q-XXXW5-7 & AP7343DQ-XXXW5-7



For AP7343DQ-XXXFDZW-7





Note: 15. The taping orientation of the other package type can be found on our website at https://www.diodes.com/assets/Packaging-Support-Docs/ap02007.pdf.



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